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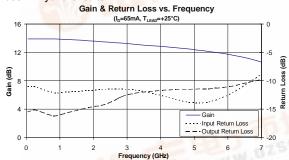


## **Product Description**

Sirenza Microdevices' SNA-486 is a GaAs HBT MMIC Amplifier housed in a low-cost, surface-mountable plastic package. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products.

The use of an external resistor allows for bias flexibility and stability. These unconditionally stable amplifiers are designed for use as general purpose 50 ohm gain blocks.

Also available in chip form (SNA-400), its small size (0.38mm x 0.38mm) and gold metallization make it an ideal choice for use in hybrid circuits.



## **SNA-486**

# DC-6.5 GHz, Cascadable GaAs MMIC Amplifier

Not Recommended for New Designs
See Application Note AN-017 for Alternates



#### **Product Features**

- Patented GaAs HBT Technology
- Cascadable 50 Ohm Gain Block
- +32dBm Ouput IP3 at 850MHz
- Operates From Single Supply
- Low Cost Surface Mount Plastic Package

## **Applications**

Cellular, PCS, CDPD, Wireless Data, SONET

Symbol	Parameter	Frequency	Units	Min.	Тур.	Max.
P <sub>1dB</sub>	Output Power at 1dB Compression	850 MHz 1950 MHz 2400 MHz	dBm dBm dBm	15.5	17.1 17.5 17.5	
OIP <sub>3</sub>	Output Third Order Intercept Point	850 MHz 1950 MHz 2400 MHz	dBm dBm dBm	27.9	32.3 30.9 30.6	电 WWW
S <sub>21</sub>	Small Signal Gain	850 MHz 1950 MHz 2400 MHz	dB dB dB	12.5 12.2	13.9 13.6 13.5	15.3 15.0
Bandwidth	(Determined by S <sub>11</sub> , S <sub>22</sub> Values)	A TOP?	MHz		6500	
VSWR <sub>IN</sub>	Input VSWR	DC-6500 MHz	-		1.7:1	
VSWR <sub>out</sub>	Output VSWR	DC-6500 MHz	-		1.6:1	
S <sub>12</sub>	Reverse Isolation	850 MHz 1950 MHz 2400 MHz	dB dB dB		18.3 18.2 18.2	
NF	Noise Figure	1950 MHz	dB		5.0	6.5
V <sub>D</sub>	Device Operating Voltage		V	4.5	5.0	5.5
<sub>∞</sub> I <sub>D</sub>	Device Operating Current		mA	58	65	72
REIF	Thermal Resistance (junction - lead)		° C/W		254	

**Test Conditions** 

V<sub>s</sub> = 8 V R<sub>---</sub> = 47 Ohms  $I_D = 65 \text{ mA Typ}$   $T = 25^{\circ}\text{C}$ 

 $OIP_3$  Tone Spacing = 1 MHz, Pout per tone = 0 dBm  $Z_s = Z_1 = 50$  Ohms



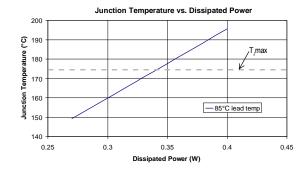
### Typical RF Performance at Key Operating Frequencies

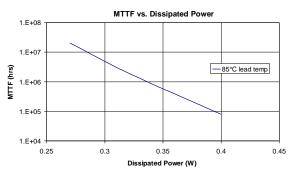
				Frequency (MHz)				
Symbol	Parameter	Unit	100	500	850	1950	2400	3500
G	Small Signal Gain	dB	13.9	13.9	13.9	13.6	13.5	13.1
OIP <sub>3</sub>	Output Third Order Intercept Point	dBm		32.0	32.3	30.9	30.6	
P <sub>1dB</sub>	Output Power at 1dB Compression	dBm		17.0	17.1	17.5	17.5	
IRL	Input Return Loss	dB	11.0	11.6	12.2	11.7	11.5	11.9
ORL	Output Return Loss	dB	15.4	15.6	16.2	14.7	14.1	12.0
S <sub>12</sub>	Reverse Isolation	dB	18.3	18.3	18.3	18.2	18.2	18.2
NF	Noise Figure	dB		5.0	5.0	5.0		
Test Conditions: $V_s = 8v$ $I_D = 65mA$			A Тур.	OIP3 Tone S	Spacing = 1	MHz, Pout	per tone = 0	) dBm

Test Conditions:  $V_s = 8v$   $V_s = 8v$   $V_s = 47 \text{ Ohms}$   $V_s = 47 \text{ Ohms}$   $V_s = 47 \text{ Ohms}$   $V_s = 8v$   $V_s = 8v$ 

Absolute Maximum Ratings	Parameter	Absolute Limit
Absolute Maximum Ratings	Max. Device Current (I <sub>D</sub> )	110 mA
Operation of this device beyond any one of these limits may	Max. Device Voltage (V <sub>D</sub> )	7 V
cause permanent damage. For reliable continous operation, the device voltage and current must not exceed the maximum	Max. RF Input Power	+16 dBm
operating values specified in the table on page one.	Max. Junction Temp. $(T_J)$	+175°C
Bias Conditions should also satisfy the following expression:	Operating Temp. Range (T <sub>L</sub> )	-40°C to +85°C
$I_D V_D < (T_J - T_L) / R_{TH}$ , j-I	Max. Storage Temp.	+150°C

**NOTE:** While the SNA-486 can be operated at different bias currents, 65 mA is the recommended bias for lower junction temperature and longer life. This reflects typical operating conditions which we have found to be an optimal balance between high IP3 and MTTF. In general, MTTF is improved to more than 100,000 hours when biasing at 65 mA and operating up to 85°C ambient temperature.

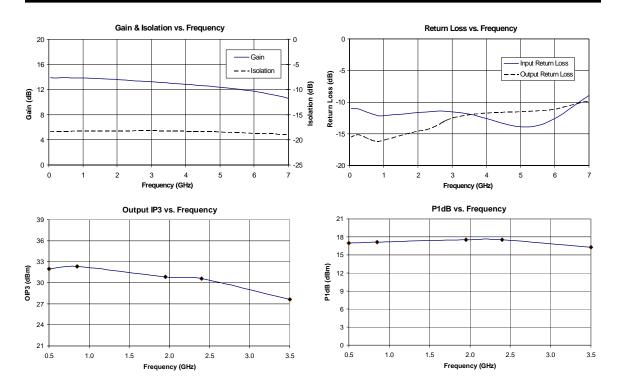


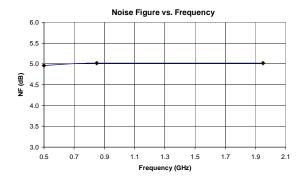




## SNA-486 DC-6.5 GHz Cascadable MMIC Amplifier

## Typical RF Performance ( $V_{DS}$ = 5.0V, $I_{DS}$ = 65mA, $T_{LEAD}$ =25° C)

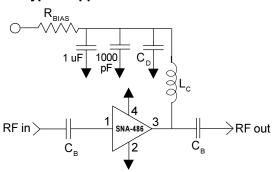


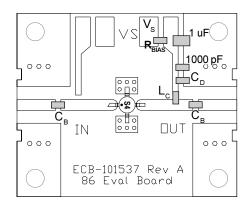




#### SNA-486 DC-6.5 GHz Cascadable MMIC Amplifier

## **Typical Application Circuit**





#### Part Identification Marking

The part will be marked with an "S4" designator on the top surface of the package.



## Caution: ESD sensitive Appropriate precautions in handling, packaging and testing devices must be observed.

#### **Application Circuit Element Values**

Reference		Frequency (Mhz)					
Designator	500	850	1950	2400	3500		
C <sub>B</sub>	220 pF	100 pF	68 pF	56 pF	39 pF		
C <sub>D</sub>	100 pF	68 pF	22 pF	22 pF	15 pF		
L <sub>c</sub>	68 nH	33 nH	22 nH	18 nH	15 nH		

Recommended Bias Resistor Values for $I_{\rm p}$ =65mA $R_{\rm BIAS}$ =( $V_{\rm s}$ - $V_{\rm p}$ ) / $I_{\rm p}$				
Supply Voltage(V <sub>s</sub> )	8 V	9 V	12 V	15 V
R <sub>BIAS</sub>	47 Ω	62 Ω	110 Ω	150Ω
Note: R provides DC bias stability over temperature.			erature.	

#### **Mounting Instructions**

- 1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

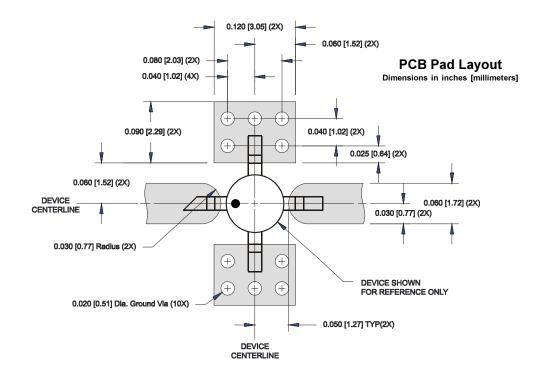
Pin#	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.

#### **Part Number Ordering Information**

Part Number	Reel Size	Devices/Reel
SNA-486-TR1	7"	1000



## SNA-486 DC-6.5 GHz Cascadable MMIC Amplifier



#### **Nominal Package Dimensions**

Dimensions in inches [millimeters]
Refer to drawing posted at www.sirenza.com for tolerances.

